

SONY**CXB1108Q**

T-52-21

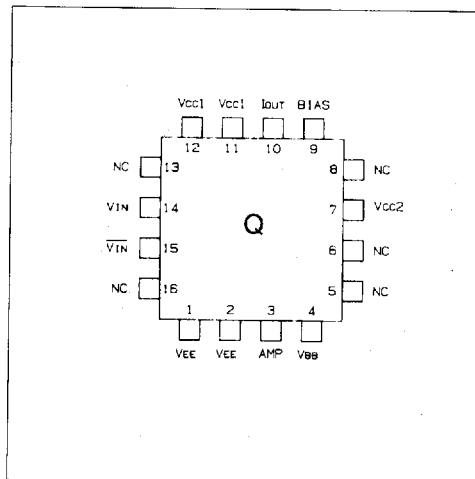
Laser Driver**Description**

The CXB1108Q is an ultra high speed monolithic Laser Driver/Current Switch Circuit with ECL input level.

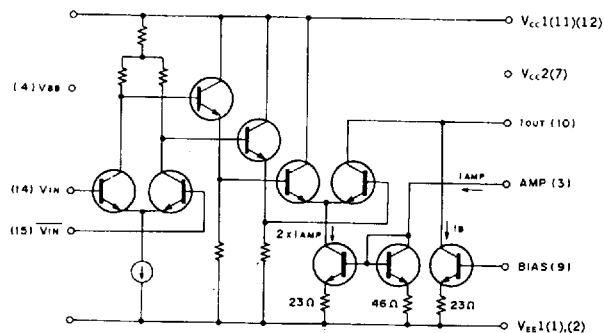
Open collector output is provided at the output pin and has a capability of driving peak-to-peak current of 60mA up to a data rate of 2Gbps (NRZ). AMP input controls the peak-to-peak current amplitude, and BIAS input sets a current bias level. Open collector output I_{OUT} sinks current of $2 \times I_{AMP} + I_B$. Data input has differential input pins (V_{IN} and $\overline{V}_{IN}$). Built-in reference voltage is provided at V_{BB} pin to facilitate the use of single input operation.

Features

- Typical data rate up to 2.0Gbps (NRZ)
- Differential Data input
- Internal pull down resistors on input pins to maintain logic LOW level with the pins left open
- ECL 100K compatible Input level

Pin Assignment**Pin Names**

V_{IN} , $\overline{V}_{IN}$	Data input
I_{OUT}	Current output
AMP	Current amplitude control input
BIAS	Bias Current control input
V_{BB}	Reference voltage output
V_{CC1}	Circuit ground
V_{EE}	Negative power supply
V_{CC2}	Reference voltage generation circuit ground

Circuit Diagram

SONY®

CXB1108Q

T-52-21

DC Characteristics

 $V_{EE} = -4.5 \pm 0.3V$, $V_{CC1} = V_{CC2} = GND$, $T_c = 0^\circ C$ to $+85^\circ C$, $R_L = 10\Omega$ to V_{CC1}

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Power supply current	I_{EE}	$V_{IN} = H, \overline{V_{IN}} = L, I_{OUT} = 100mA, I_{AMP} = 25mA$	-224	-164	-114	mA
Output Current	I_{OUT}		0		120	mA
		$I_{AMP} = 0 \quad V_{AMP} = V_{EE}$	0		60	
		$I_B = 0 \quad V_{BIAS} = V_{EE}$	0		60	
Input voltage range	V_{IN}		-2.0		-0.5	V
Reference bias voltage	V_{BS}		-1380	-1320	-1160	mV

Note: Other DC characteristics; See pages 3-3 and 3-4.

AC Characteristics

 $V_{EE} = -4.5 \pm 0.3V$, $V_{CC1} = V_{CC2} = GND$, $T_c = 0^\circ C$ to $+85^\circ C$, $R_L = 50\Omega$ to V_{CC1}

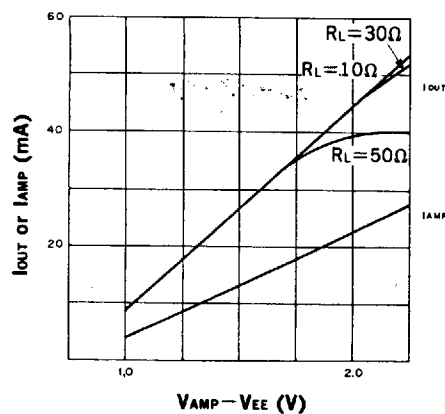
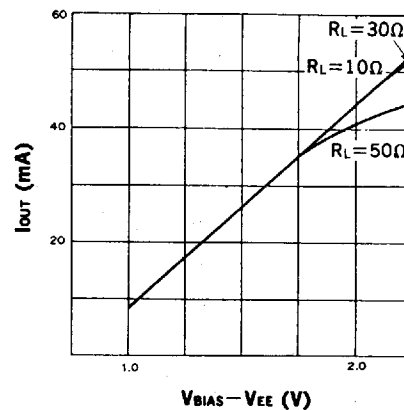
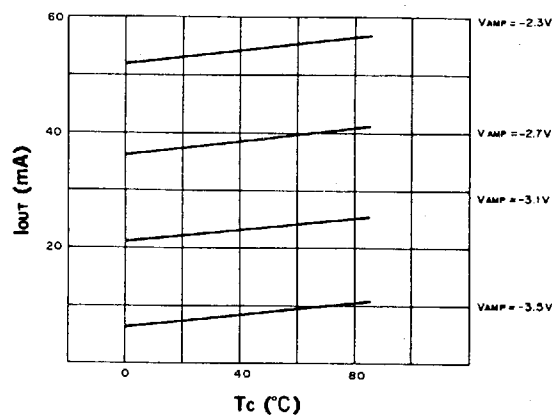
Item	Symbol	Input	Output	Test Condition	Min.	Typ.	Max.	Unit
Max. Data rate	f_{DMAX}	V_{IN}	I_{OUT}	NRZ	1.7	2.0		Gbps
Rise time	T_{TLH}			20% to 80%		200	240	ps
Fall time	T_{THL}					200	240	

Note: AC test circuit; See page 4-3.

SONY®

CXB1108Q

T-52-21

Figure 1. $V_{AMP} - V_{EE}$ vs I_{OUT}
(BIAS = Open)Figure 2. $V_{BIAS} - V_{EE}$ vs I_{OUT}
(AMP = Open)Figure 3. T_c vs I_{OUT}

Package Data

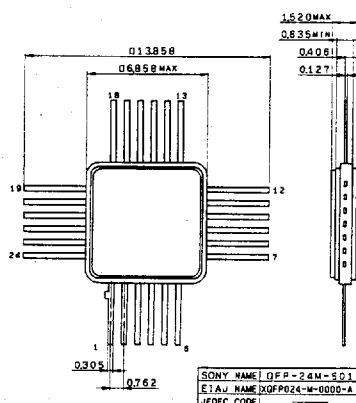
T-90-20

Package Outline

Unit: mm

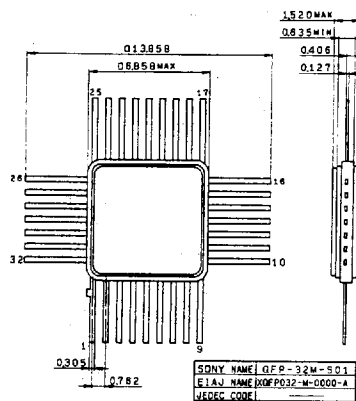
24pin QFP (QFP-24M-S01)

24pin QFP (Metal) 0.3g



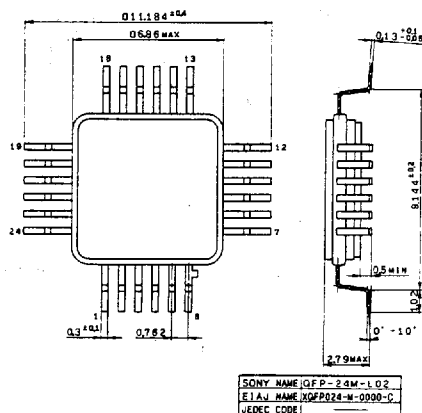
32pin QFP (QFP-32M-S01)

32pin QFP (Metal) 0.2g



24pin QFP (QFP-24M-L02)

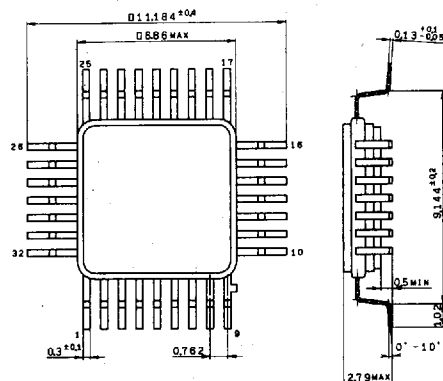
24pin QFP (Metal) 0.3g



T-90-20

32pin QFP (QFP-32M-L02)

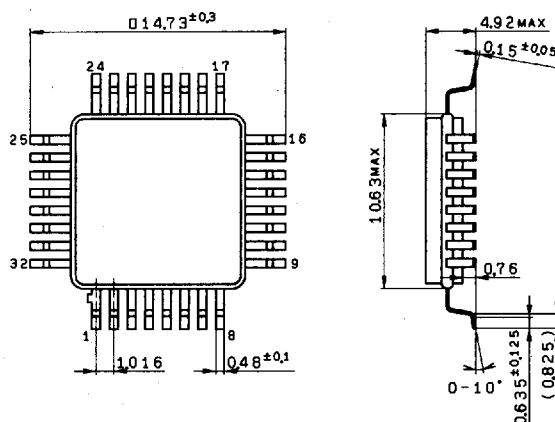
32pin QFP (Metal) 0.2g



SONY NAME	QFP-32M-L02
EIAJ NAME	XQFP032-M-0000-C
JEDEC CODE	

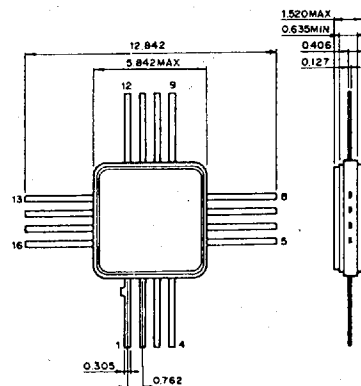
32pin QFP (QFP-32C-L01)

32pin QFP (Ceramic)



SONY NAME	QFP-32C-L01
EIAJ NAME	XQFP032-G-0000-A
JEDEC CODE	

16pin QFP



Package Data

Package Data	Page
1. 16 pin QFP	6-3
2. 24 pin QFP	6-3
3. 32 pin QFP	6-3
4. 24 pin QFP with formed lead	6-4
5. 32 pin QFP with formed lead	6-4

Package Data

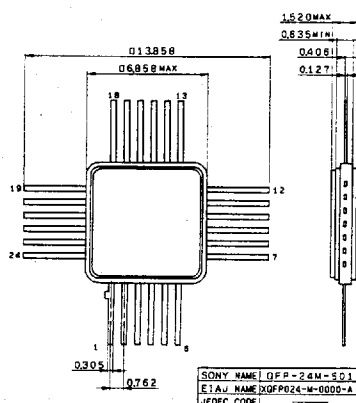
T-90-20

Package Outline

Unit: mm

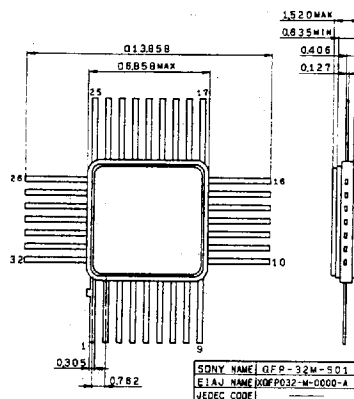
24pin QFP (QFP-24M-S01)

24pin QFP (Metal) 0.3g



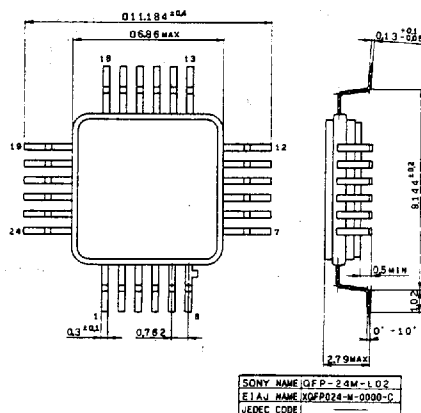
32pin QFP (QFP-32M-S01)

32pin QFP (Metal) 0.2g



24pin QFP (QFP-24M-L02)

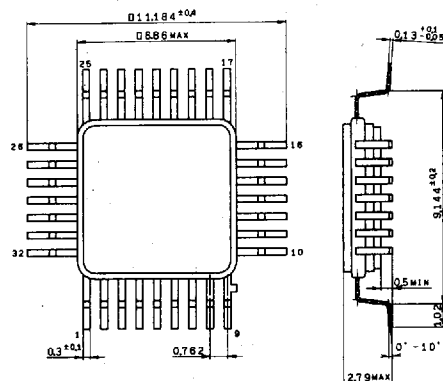
24pin QFP (Metal) 0.3g



T-90-20

32pin QFP (QFP-32M-L02)

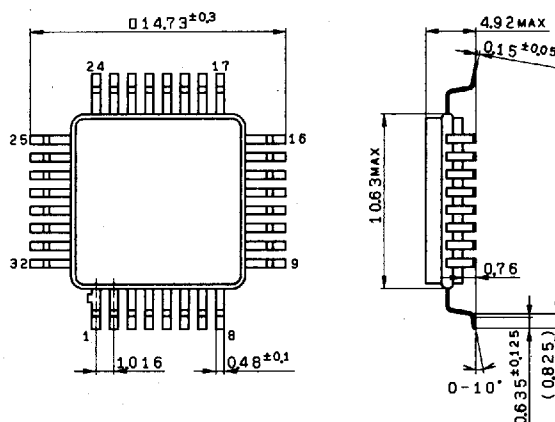
32pin QFP (Metal) 0.2g



SONY NAME	QFP-32M-L02
EIAJ NAME	XQFP032-M-0000-C
JEDEC CODE	

32pin QFP (QFP-32C-L01)

32pin QFP (Ceramic)



SONY NAME	QFP-32C-L01
EIAJ NAME	XQFP032-G-0000-A
JEDEC CODE	

16pin QFP

